

X4-Class **Power MOSFET™**

IXTH94N20X4

N-Channel Enhancement Mode Avalanche Rated



$V_{\rm DSS}$	=	200V
I _{D25}	=	94A
R _{DS(on)}	≤	10.6m Ω



TO-247 (IXTH)	
G	
D s	D (Tab)

G = Gate	D	= Drain
S = Source	Tab	= Drain

Fe	a	tu	ire	S

- International Standard Package
- Low $R_{\rm DS(ON)}$ and $Q_{\rm G}$ Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol	Test Conditions	Maximum Ra	atings
V _{DSS}	T _J = 25°C to 175°C	200	V
\mathbf{V}_{DGR}	$T_J = 25^{\circ}C$ to 175°C, $R_{GS} = 1M\Omega$	200	V
V _{GSS}	Continuous	±20	V
V _{GSM}	Transient	±30	V
I _{D25}	T _C = 25°C	94	A
I _{DM}	$\rm T_{_{\rm C}}$ = 25°C, Pulse Width Limited by $\rm T_{_{\rm JM}}$	220	Α
I _A	T _C = 25°C	47	Α
E _{as}	T _c = 25°C	1	J
dv/dt	$I_{_{S}} \le I_{_{DM}}, V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} \le 150^{\circ}C$	20	V/ns
P _D	T _C = 25°C	360	W
T _J		-55 +175	°C
T _{JM}		175	°C
T _{stg}		-55 +175	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
	1.6 mm (0.062 in.) from Case for 10s		
M _d	Mounting Torque	1.13 / 10	Nm/lb.in
Weight		6	g

Symbol (T _J = 25°C	Test Conditions , Unless Otherwise Specified)	Charad Min.	cteristic Typ.	Values Max	
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	200			V
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250\mu A$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA
DSS	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 150^{\circ}C$			20 500	μ Α μ Α
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			10.6	mΩ

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Symbol Test Conditions Chara		acteristic Values		
$(T_{J} = 25^{\circ}C, L)$	Inless Otherwise Specified)	Min.	Тур.	Max
g _{fs}	$V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$	60	100	S
R _{Gi}	Gate Input Resistance		5.3	Ω
C _{iss}			5050	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		750	pF
C _{rss}			4	pF
	Effective Output Capacitance			
$\mathbf{C}_{o(er)}$	Energy related $\int V_{GS} = 0V$		390	pF
$\mathbf{C}_{\mathrm{o(tr)}}$	Time related $V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		1670	pF
t _{d(on)}	Resistive Switching Times		18	ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		9	ns
t _{d(off)}	$R_{\rm G} = 5\Omega$ (External)		97	ns
t _f	N _G = 322 (External)		7	ns
$Q_{g(on)}$			77	nC
Q _{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		21	nC
\mathbf{Q}_{gd}			25	nC
R _{thJC}				0.42 °C/W
R _{thcs}			0.21	°C/W

Source-Drain Diode

Symbol	Test Conditions	Chara	cteristic	Values	
$(T_{J} = 25^{\circ}C, U)$	Inless Otherwise Specified)	Min.	Тур.	Max	
I _s	$V_{GS} = 0V$			94	Α
SM	Repetitive, pulse Width Limited by $T_{_{\rm JM}}$			376	A
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.4	V
$\left. egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} \right\}$	$I_F = 47A$, -di/dt = 200A/ μ s $V_R = 100V$		130 1.1 17		ns µC A

Note: 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.

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Fig. 1. Output Characteristics @ $T_J = 25$ °C

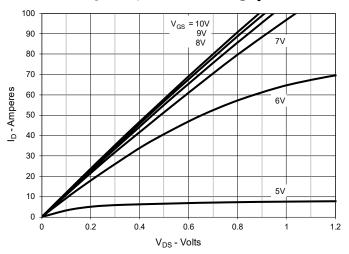


Fig. 3. Output Characteristics @ $T_J = 150$ °C

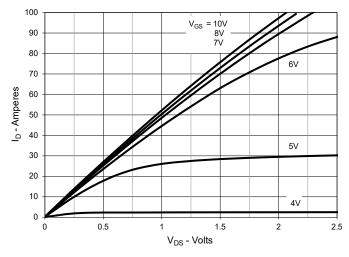


Fig. 5. $R_{DS(on)}$ Normalized to I_D = 47A Value vs. Drain Current

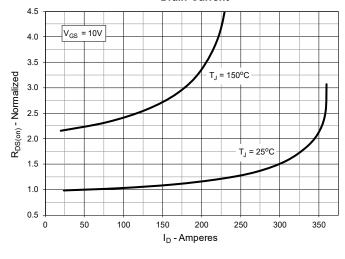


Fig. 2. Extended Output Characteristics @ $T_J = 25$ °C

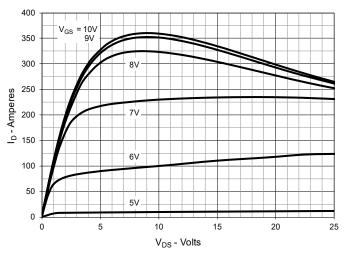


Fig. 4. $R_{DS(on)}$ Normalized to I_D = 47A Value vs. Junction Temperature

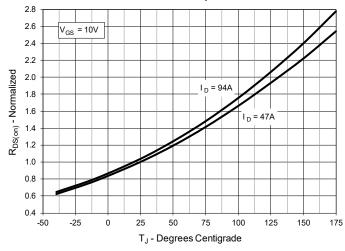
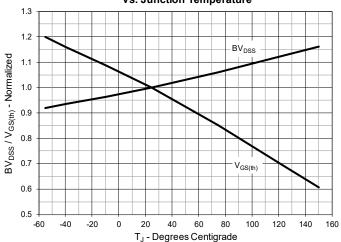
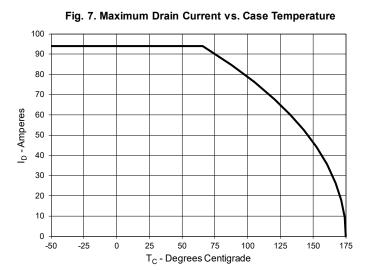


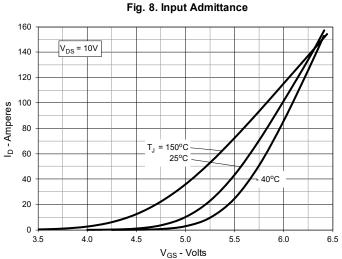
Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature

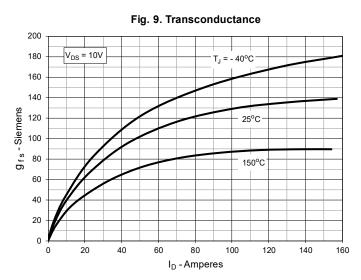


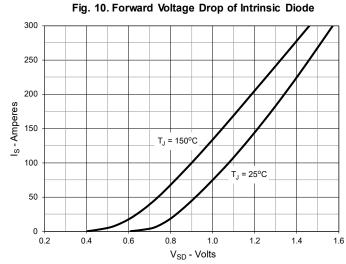
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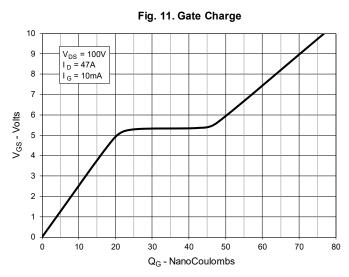


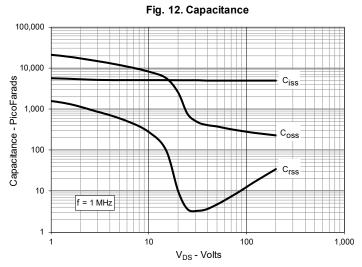












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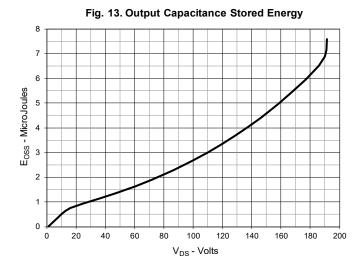


Fig. 14. Forward-Bias Safe Operating Area

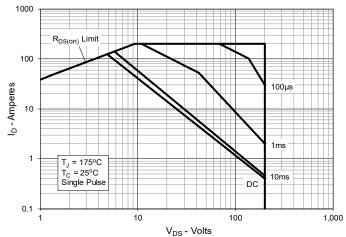
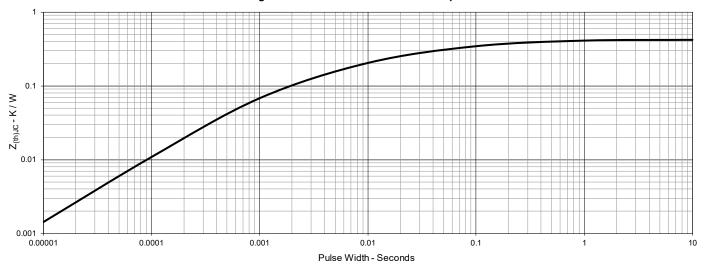


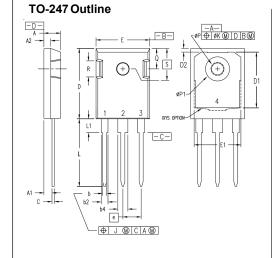
Fig. 15. Maximum Transient Thermal Impedance



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1 - Gate 2,4 - Drain

3 - Source

SYM	INC	HES	INC	HES
OTIVI	MIN	MAX	MIN	MAX
Α	0.190	0.205	4.83	5.21
A1	0.090	0.100	2.29	2.54
A2	0.075	0.085	1.91	2.16
b	0.045	0.055	1.14	1.40
b2	0.075	0.087	1.91	2.20
b4	0.115	0.126	2.92	3.20
С	0.024	0.031	0.61	0.80
D	0.819	0.840	20.80	21.34
D1	0.650	0.690	16.51	17.53
D2	0.035	0.050	0.89	1.27
E	0.620	0.635	15.57	16.13
E1	0.545	0.565	13.84	14.35
е	0.215 BSC		5.45	BSC
J	255	0.010	243	0.250
K	255	0.025	243	0.640
L	0.780	0.810	19.81	20.57
L1	0.150	0.170	3.81	4.32
ØP	0.140	0.144	3.55	3.65
ØP1	0.275	0.290	6.99	7.37
Q	0.220	0.244	5.59	6.20
R	0.170	0.190	4.32	4.83
S	0.242	BSC	6.15	BSC



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